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(54) **OLED DISPLAY WITH CIRCULAR POLARIZER**

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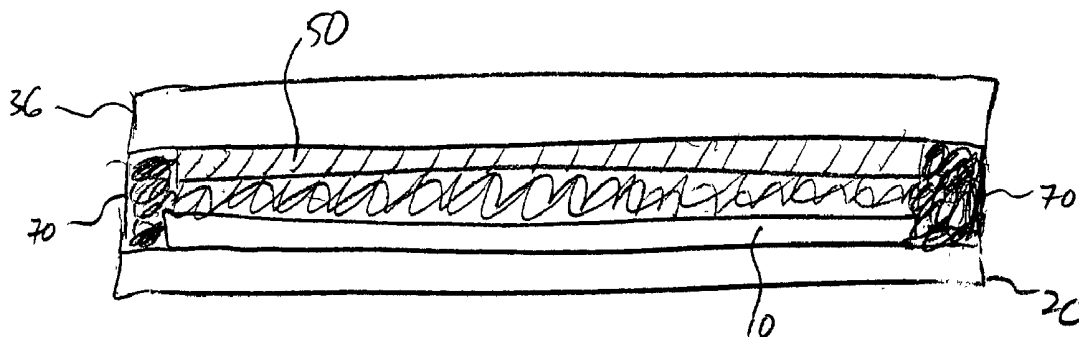
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(57) **ABSTRACT**

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A top emitting OLED display includes a substrate; an array of OLED light emissive elements formed over the substrate; an encapsulating cover located over the OLED light emissive elements; and a circular polarizer located between the encapsulating cover and the OLED light emissive elements.

(21) Appl. No.: **10/271,149**



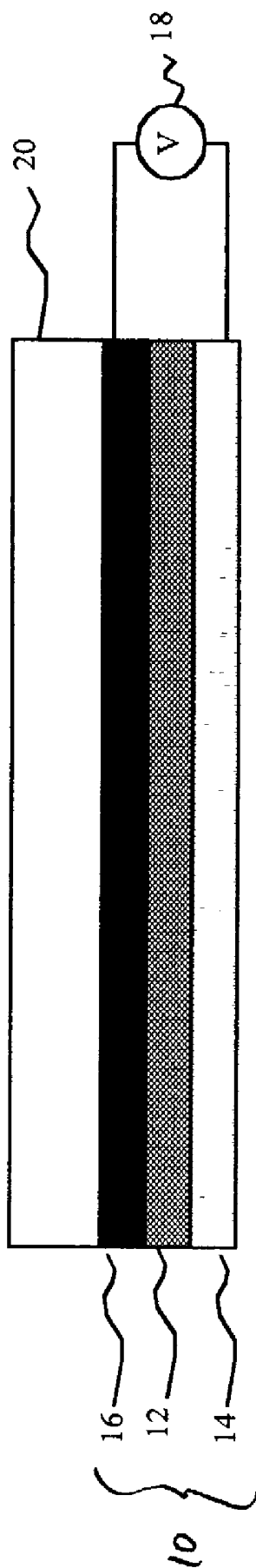


FIG. 1
(PRIOR ART)

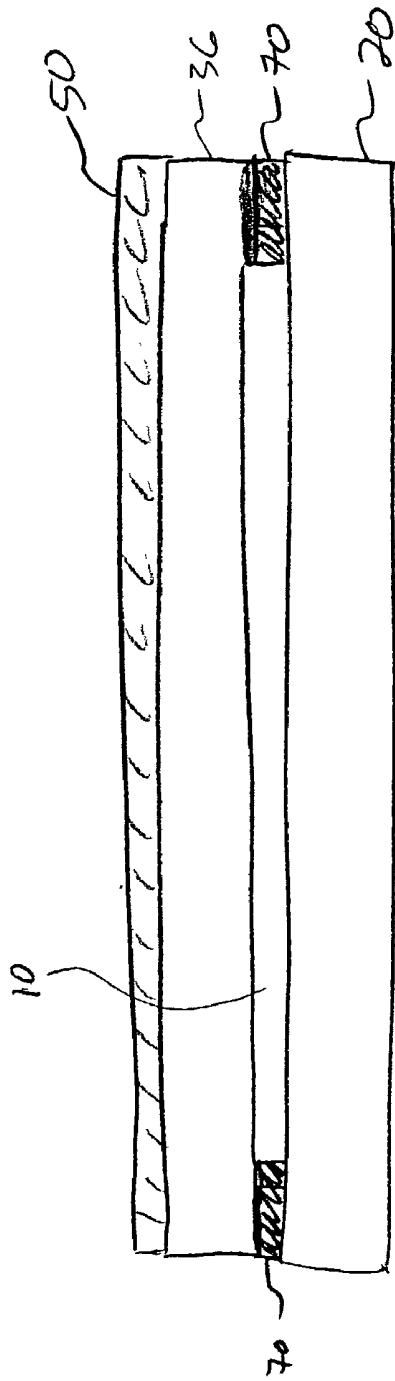


FIG. 3

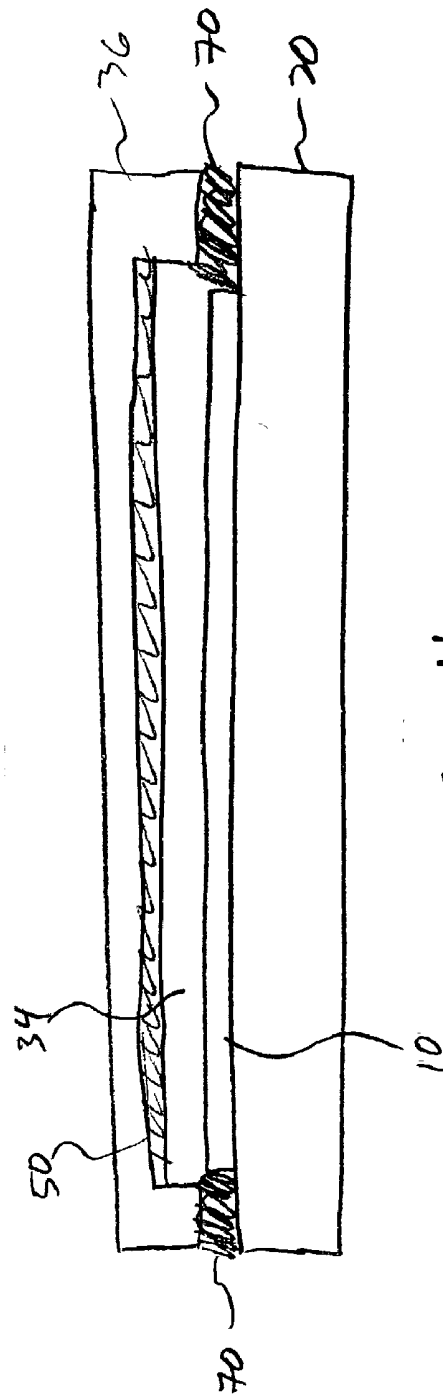


FIG. 4

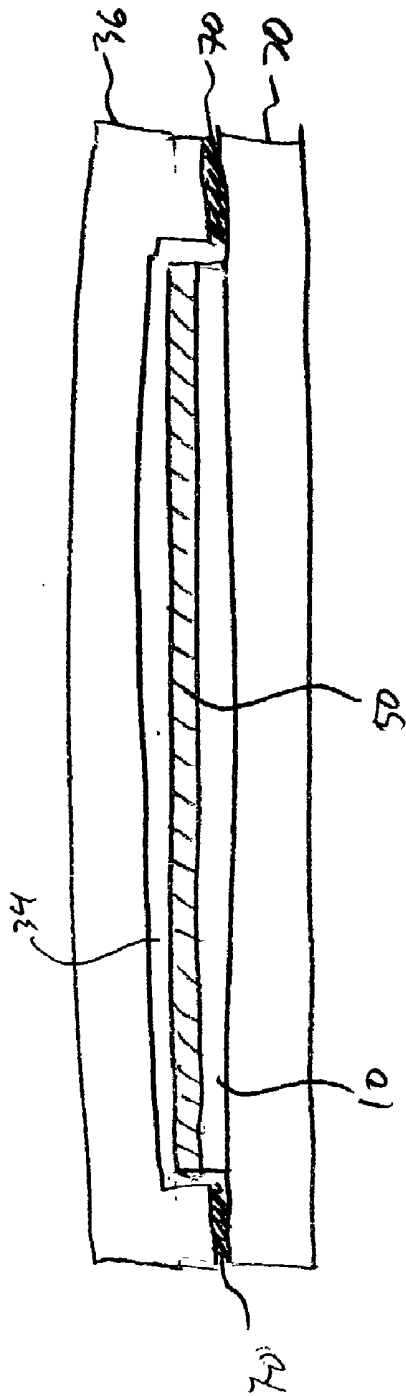


FIG. 5

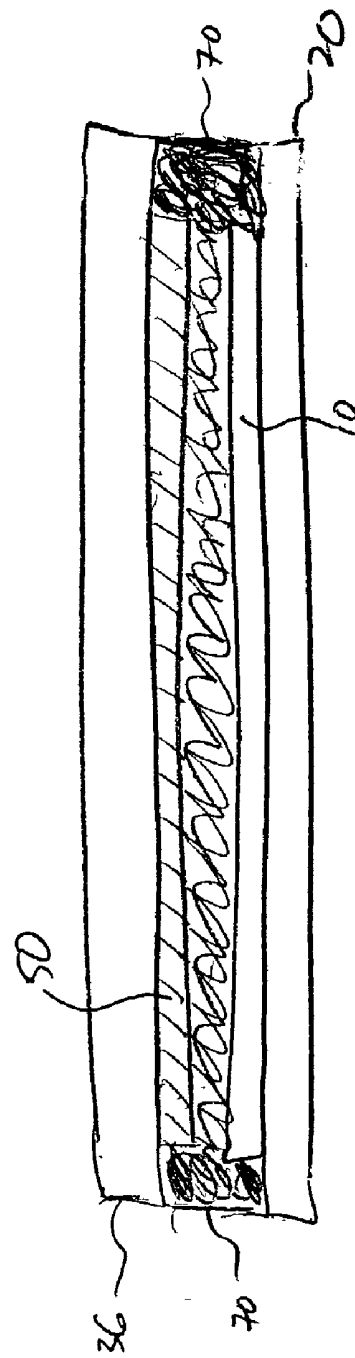
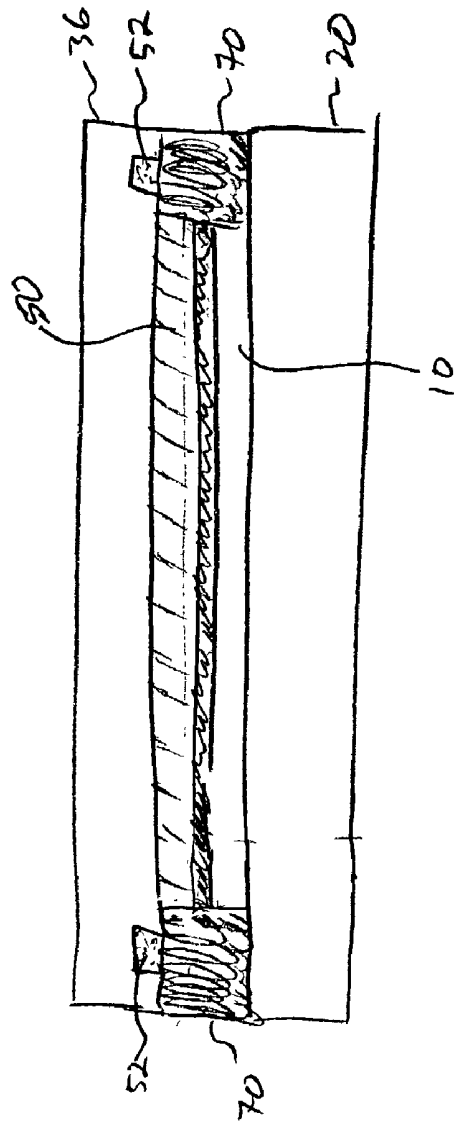
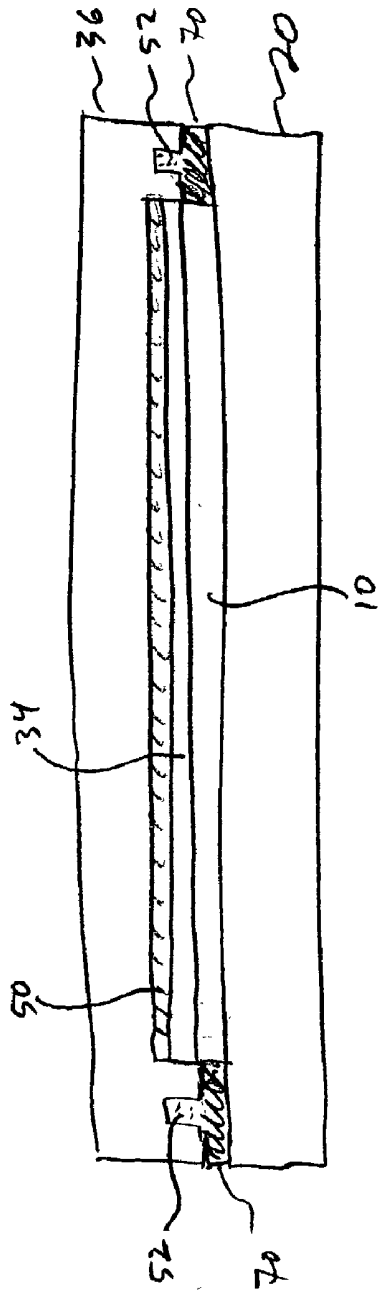


FIG. 6



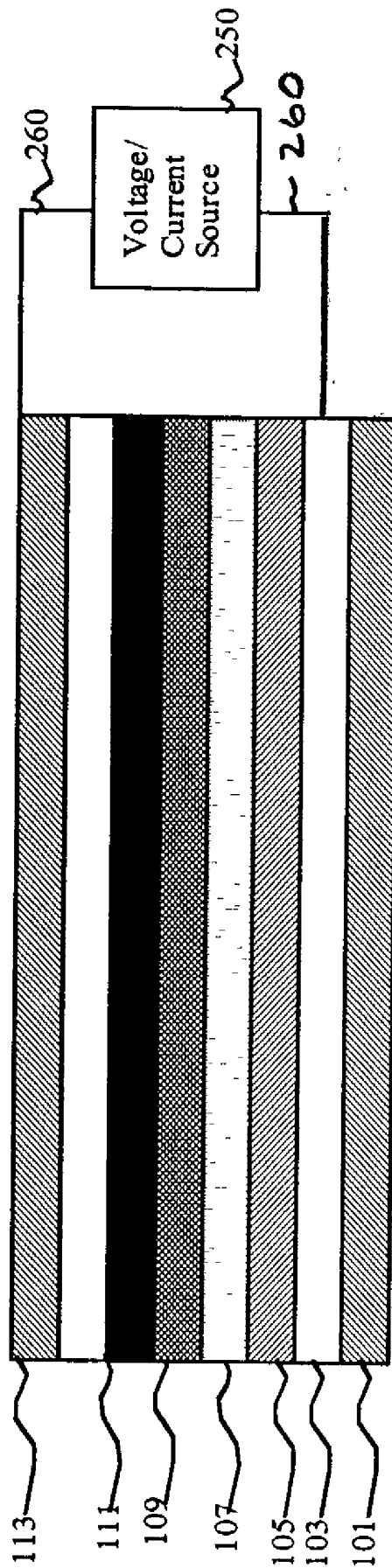


FIG. 9
(PRIOR ART)

OLED DISPLAY WITH CIRCULAR POLARIZER

FIELD OF THE INVENTION

[0001] The present invention relates to organic light emitting diode (OLED) displays and, more particularly, to such displays having circular polarizing elements to reduce glare and increase the display contrast.

BACKGROUND OF THE INVENTION

[0002] Emissive flat-panel display devices are widely used in conjunction with computing devices and in particular with portable devices. These displays are often used in portable devices or in public areas with significant ambient illumination. In these locations, the contrast of the display is of great concern.

[0003] In particular, OLED display devices suffer from problems with contrast. It is known to use a circular polarizer affixed to the surface of the display so that light incident on the display is absorbed by the polarizer, while light emitted by the display is not. This is problematic in that the circular polarizer is exposed to the environment and is subject to scratching, peeling, moisture, dents, and the like, which reduces its effectiveness and acceptability.

[0004] In an attempt to address the problem, WO0210845 A2 entitled "High Durability Circular Polarizer for use with Emissive Displays" published Feb. 7, 2002 describes a high durability circular polarizer including an unprotected K-type polarizer and a quarter-wavelength retarder and designed for use with an emissive display module such as an organic light emitting diode or a plasma display device. Such devices are expensive and remain subject to environmental stress which can degrade their performance. Moreover, placing a circular polarizer on the surface of the display device inhibits the further integration of other elements such as lenslet arrays and touch screen components over the display.

[0005] There is a need therefore for an improved OLED display that improves the robustness of the display while maintaining the display contrast.

SUMMARY OF THE INVENTION

[0006] The need is met according to the present invention by providing a top emitting OLED display that includes a substrate; an array of OLED light emissive elements formed over the substrate; an encapsulating cover located over the OLED light emissive elements; and a circular polarizer located between the encapsulating cover and the OLED light emissive elements.

ADVANTAGES

[0007] The present invention has the advantage that it improves the robustness of an OLED display by protecting the circular polarizer from environmental wear and enables the application of additional structures on the top of the encapsulating cover.

BRIEF DESCRIPTION OF THE DRAWINGS

[0008] FIG. 1 is a schematic diagram of a prior-art OLED;

[0009] FIG. 2 is a partial cross section of a prior-art top-emitting OLED display device;

[0010] FIG. 3 is a cross section of a top-emitting OLED display device with a circular polarizer located on the top of the display as suggested by the prior art;

[0011] FIG. 4 is a cross section of a top-emitting OLED display according to one embodiment of the present invention;

[0012] FIG. 5 is a cross section of a top-emitting OLED display according to an alternative embodiment of the present invention;

[0013] FIG. 6 is a cross section of a top-emitting OLED display according to yet another alternative embodiment of the present invention;

[0014] FIG. 7 is a cross section of a top-emitting OLED display according to yet another alternative embodiment of the present invention;

[0015] FIG. 8 is a cross section of a top-emitting OLED display according to yet another alternative embodiment of the present invention; and

[0016] FIG. 9 is a partial cross section of a prior art OLED emitter having multiple layers.

DETAILED DESCRIPTION OF THE INVENTION

[0017] Referring to FIG. 1, a prior art OLED includes a substrate 20 such as glass or plastic and an OLED light emissive element 10 having an organic light-emitting layer 12 disposed between two electrodes, e.g. a cathode 14 and an anode 16. The organic light emitting layer 12 emits light upon application of a voltage from a power source 18 across the electrodes. It will be understood that the relative locations of the electrodes 14 and 16 may be reversed with respect to the substrate. The light-emitting layer 12 may include other layers such as electron or hole injection layers as is known in the art.

[0018] Referring to FIG. 2, a prior art top-emitting OLED display device 11 includes a substrate 20, a thin-film transistor (TFT) active matrix layer 22 that provides power to an OLED light emitting layer 12. A patterned first planarizing insulating layer 24 is provided over the TFT active matrix layer, and an array of first electrodes 16 are provided over the planarized insulating layer 24 and in electrical contact with the TFT active matrix layer. A patterned second insulating layer 24' is provided over the array of first electrodes 16 such that at least a portion of the each of the first electrodes 16 is exposed and the various electrodes 16 do not form an electrical short circuit.

[0019] Over the first electrodes and insulating layers are provided red, green, and blue-emitting organic OLED elements, 12R, 12G, and 12B, respectively. These elements are composed of further layers as described in more detail below. Herein, the collection of OLED elements, including hole injection 26, hole transport 27, electron injection 29, and electron transport layers 28, may also be referred to as the OLED light-emitting layer 12. The light-emitting area is generally defined by the area of the first electrode 16 in contact with the OLED elements. Over the OLED light-emitting layer 12 is provided a transparent, common second electrode 14 that has sufficient optical transparency to allow transmission of the generated red, green, and blue light. An optional second electrode protection layer 32 may be pro-

vided to protect the electrode and underlying layers. Each first electrode in combination with its associated OLED element and second electrode is herein referred to as an OLED light emissive element **10**. A typical top-emitting OLED display device comprises an array of OLED light emitting elements wherein each OLED light emitting elements emits red, green or blue light. A cavity **34** generally filled with inert gas or a transmissive polymer material, separates the optional electrode protection layer from an encapsulating cover **36**.

[0020] Referring to **FIG. 3**, a prior art top-emitting OLED may be provided with a circular polarizer **50** that has the property that it will polarize light that passes through the polarizer and will absorb such polarized light that is reflected from the OLED light emissive elements **10** or substrate **20**. About half of the light emitted from the light emissive elements **10** passes through the circular polarizer, but most of the ambient light falling on the device is absorbed by the circular polarizer. As noted above, the problem with this arrangement is that the circular polarizer is subjected to the external environment and can be easily scratched or and is subject to delamination from the surface of the display device.

[0021] Referring to **FIG. 4**, according to the present invention, the circular polarizer **50** is located between the encapsulating cover and the OLED light emissive elements, thereby protecting the circular polarizer from the environment. In the preferred embodiment, the encapsulating cover **36** defines a cavity **34** and is affixed to the substrate **20** by a suitable adhesive **70**, typically an epoxy. The cavity **34** may be sufficiently deep to leave a gap between the circular polarizer **50** and the OLED light emissive elements **10**. The present invention may include the optional electrode protection layer **32** shown in **FIG. 2** to further protect the electrode **14** and layers beneath the electrode. Moreover, the adhesive **70**, if it is sufficiently transparent may be used to fill the cavity **34** between the circular polarizer and the OLED light emissive elements **10**. The circular polarizer **50** may be attached to the inside of the encapsulating cover **36** with a suitable adhesive.

[0022] Referring to **FIG. 5**, in an alternative embodiment of the present invention, the circular polarizer **50** is located on top of the OLED light emissive elements **10**.

[0023] Referring to **FIG. 6**, in a still further alternative embodiment of the present invention, the encapsulating cover **36** does not define a cavity. The circular polarizer **50** is attached to the encapsulating cover **36**. A transparent adhesive layer **70** hermetically seals the perimeter of the encapsulating cover over the OLED light emissive elements **10** and may extend over the OLED light emissive elements **10**. Alternatively, the circular polarizer **50** may be attached to the OLED light emissive elements **10** and the transparent adhesive extends between the circular polarizer and the encapsulating cover. According to a further alternative, the adhesive **70** may be located only around the periphery of the encapsulating cover and can comprise a light absorbing material.

[0024] Referring to **FIGS. 7 and 8**, the encapsulating cover **36** may be provided with a peripheral channel **52** that is filled with a desiccant material. **FIG. 7** shows such an arrangement wherein the encapsulating cover defines a cavity over the OLED light emissive elements, and **FIG. 8**

shows the arrangement wherein the encapsulating cover does not. In either case, a gap filled with an inert gas or light transmissive material may be provided between the circular polarizer and the encapsulating cover or the OLED light emissive elements. The circular polarizer may be affixed to the OLED light emissive elements **10** as shown in **FIG. 5**.

[0025] In a preferred embodiment, the invention is employed in a device that includes Organic Light Emitting Diodes (OLEDs) which are composed of small molecule or polymeric OLEDs as disclosed in but not limited to U.S. Pat. No. 4,769,292, issued Sep. 6, 1988 to Tang et al. and U.S. Pat. No. 5,061,569, issued Oct. 29, 1991 to VanSlyke et al. Many combinations and variations of organic light emitting displays can be used to fabricate such a device.

[0026] General Device Architecture

[0027] The present invention can be employed in most OLED material configurations. These include very simple structures comprising a single anode and cathode to more complex devices, such as passive matrix displays comprised of orthogonal arrays of anodes and cathodes to form pixels, and active-matrix displays where each pixel is controlled independently, for example, with thin film transistors (TFTs).

[0028] There are numerous configurations of the organic layers wherein the present invention can be successfully practiced. A typical structure is shown in **FIG. 9** and is comprised of a substrate **101**, an anode **103**, a hole-injecting layer **105**, a hole-transporting layer **107**, a light-emitting layer **109**, an electron-transporting layer **111**, and a cathode **113**. These layers are described in detail below. Note that the substrate may alternatively be located adjacent to the cathode, or the substrate may actually constitute the anode or cathode. The organic layers between the anode and cathode are conveniently referred to as the organic EL element. The total combined thickness of the organic layers is preferably less than 500 nm.

[0029] The anode and cathode of the OLED are connected to a voltage/current source **250** through electrical conductors **260**. The OLED is operated by applying a potential between the anode and cathode such that the anode is at a more positive potential than the cathode. Holes are injected into the organic EL element from the anode and electrons are injected into the organic EL element at the cathode. Enhanced device stability can sometimes be achieved when the OLED is operated in an AC mode where, for some time period in the cycle, the potential bias is reversed and no current flows. An example of an AC driven OLED is described in U.S. Pat. No. 5,552,678.

[0030] Substrate

[0031] The OLED device of this invention is typically provided over a supporting substrate where either the cathode or anode can be in contact with the substrate. The electrode in contact with the substrate is conveniently referred to as the bottom electrode. Conventionally, the bottom electrode is the anode, but this invention is not limited to that configuration. The substrate can either be transmissive or opaque. In the case wherein the substrate is transmissive, a reflective or light absorbing layer is used to reflect the light through the encapsulating cover or to absorb the light, thereby improving the contrast of the display. Substrates can include, but are not limited to, glass, plastic,

semiconductor materials, silicon, ceramics, and circuit board materials. Of course it is necessary to provide a light-transparent top electrode.

[0032] Anode

[0033] When EL emission is viewed through anode **103**, the anode should be transparent or substantially transparent to the emission of interest. Common transparent anode materials used in this invention are indium-tin oxide (ITO), indium-zinc oxide (IZO) and tin oxide, but other metal oxides can work including, but not limited to, aluminum- or indium-doped zinc oxide, magnesium-indium oxide, and nickel-tungsten oxide. In addition to these oxides, metal nitrides, such as gallium nitride, and metal selenides, such as zinc selenide, and metal sulfides, such as zinc sulfide, can be used as the anode. For applications where EL emission is viewed only through the cathode electrode, the transmissive characteristics of anode are immaterial and any conductive material can be used, transparent, opaque or reflective. Example conductors for this application include, but are not limited to, gold, iridium, molybdenum, palladium, and platinum. Typical anode materials, transmissive or otherwise, have a work function of 4.1 eV or greater. Desired anode materials are commonly deposited by any suitable means such as evaporation, sputtering, chemical vapor deposition, or electrochemical means. Anodes can be patterned using well-known photolithographic processes. Optionally, anodes may be polished prior to application of other layers to reduce surface roughness so as to minimize shorts or enhance reflectivity.

[0034] Hole-Injecting Layer (HIL)

[0035] While not always necessary, it is often useful to provide a hole-injecting layer **105** between anode **103** and hole-transporting layer **107**. The hole-injecting material can serve to improve the film formation property of subsequent organic layers and to facilitate injection of holes into the hole-transporting layer. Suitable materials for use in the hole-injecting layer include, but are not limited to, porphyrinic compounds as described in U.S. Pat. No. 4,720,432, plasma-deposited fluorocarbon polymers as described in U.S. Pat. No. 6,208,075, and some aromatic amines, for example, m-MTDATA (4,4',4"-tris[(3-methylphenyl)phenylamino]triphenylamine). Alternative hole-injecting materials reportedly useful in organic EL devices are described in EP 0 891 121 A1 and EP 1 029 909 A1.

[0036] Hole-Transporting Layer (HTL)

[0037] The hole-transporting layer **107** contains at least one hole-transporting compound such as an aromatic tertiary amine, where the latter is understood to be a compound containing at least one trivalent nitrogen atom that is bonded only to carbon atoms, at least one of which is a member of an aromatic ring. In one form the aromatic tertiary amine can be an arylamine, such as a monoarylamine, diarylamine, triarylamine, or a polymeric arylamine. Exemplary monomeric triarylaminines are illustrated by Klupfel et al. in U.S. Pat. No. 3,180,730. Other suitable triarylaminines substituted with one or more vinyl radicals and/or comprising at least one active hydrogen containing group are disclosed by Brantley et al. in U.S. Pat. No. 3,567,450 and 3,658,520.

[0038] A more preferred class of aromatic tertiary amines are those which include at least two aromatic tertiary amine moieties as described in U.S. Pat. No. 4,720,432 and 5,061,

569. The hole-transporting layer can be formed of a single or a mixture of aromatic tertiary amine compounds. Illustrative of useful aromatic tertiary amines are the following:

[0039] 1,1-Bis(4-di-p-tolylaminophenyl)cyclohexane

[0040] 1,1-Bis(4-di-p-tolylaminophenyl)-4-phenylcyclohexane

[0041] 4,4'-Bis(diphenylamino)quadruphenyl

[0042] Bis(4-dimethylamino-2-methylphenyl)-phenylmethane

[0043] N,N,N-Tri(p-tolyl)amine

[0044] 4-(di-p-tolylamino)-4'-[4(di-p-tolylamino)-styryl]stilbene

[0045] N,N,N',N'-Tetra-p-tolyl-4-4'-diaminobiphenyl

[0046] N,N,N',N'-Tetraphenyl-4,4'-diaminobiphenyl

[0047] N,N,N',N'-tetra-1-naphthyl-4,4'-diaminobiphenyl

[0048] N,N,N',N'-tetra-2-naphthyl-4,4'-diaminobiphenyl

[0049] N-Phenylcarbazole

[0050] 4,4'-Bis[N-(1-naphthyl)-N-phenylamino]biphenyl

[0051] 4,4'-Bis[N-(1-naphthyl)-N-(2-naphthyl)amino]biphenyl

[0052] 4,4"-Bis[N-(1-naphthyl)-N-phenylamino]-p-terphenyl

[0053] 4,4'-Bis[N-(2-naphthyl)-N-phenylamino]biphenyl

[0054] 4,4'-Bis[N-(3-acenaphthenyl)-N-phenylamino]biphenyl

[0055] 1,5-Bis[N-(1-naphthyl)-N-phenylamino]naphthalene

[0056] 4,4'-Bis[N-(9-anthryl)-N-phenylamino]biphenyl

[0057] 4,4"-Bis[N-(1-anthryl)-N-phenylamino]-p-terphenyl

[0058] 4,4'-Bis[N-(2-phenanthryl)-N-phenylamino]biphenyl

[0059] 4,4'-Bis[N-(8-fluoranthenyl)-N-phenylamino]biphenyl

[0060] 4,4'-Bis[N-(2-pyrenyl)-N-phenylamino]biphenyl

[0061] 4,4'-Bis[N-(2-naphthacenyl)-N-phenylamino]biphenyl

[0062] 4,4'-Bis[N-(2-perylenyl)-N-phenylamino]biphenyl

[0063] 4,4'-Bis[N-(1-corononyl)-N-phenylamino]biphenyl

[0064] 2,6-Bis(di-p-tolylamino)naphthalene

[0065] 2,6-Bis[di-(1-naphthyl)amino]naphthalene

[0066] 2,6-Bis[N-(1-naphthyl)-N-(2-naphthyl-amino)]naphthalene

[0067] N,N,N',N'-Tetra(2-naphthyl)-4,4"-diamino-p-terphenyl

[0068] 4,4'-Bis {N-phenyl-N-[4-(1-naphthyl)-phenyl]amino}biphenyl

[0069] 4,4'-Bis[N-phenyl-N-(2-pyrenyl)amino]biphenyl

[0070] 2,6-Bis[N,N-di(2-naphthyl)amine]fluorene

[0071] 1,5-Bis[N-(1-naphthyl)-N-phenylamino]naphthalene

[0072] 4,4',4"-tris[(3-methylphenyl)phenylamino]triphenylamine

[0073] Another class of useful hole-transporting materials includes polycyclic aromatic compounds as described in EP 1 009 041. Tertiary aromatic amines with more than two amine groups may be used including oligomeric materials. In addition, polymeric hole-transporting materials can be used such as poly(N-vinylcarbazole) (PVK), polythiophenes, polypyrrole, polyaniline, and copolymers such as poly(3,4-ethylenedioxythiophene)/poly(4-styrenesulfonate) also called PEDOT/PSS.

[0074] Light-Emitting Layer (LEL)

[0075] As more fully described in U.S. Pat. No. 4,769,292 and 5,935,721, the light-emitting layer (LEL) 109 of the organic EL element includes a luminescent or fluorescent material where electroluminescence is produced as a result of electron-hole pair recombination in this region. The light-emitting layer can be comprised of a single material, but more commonly consists of a host material doped with a guest compound or compounds where light emission comes primarily from the dopant and can be of any color. The host materials in the light-emitting layer can be an electron-transporting material, as defined below, a hole-transporting material, as defined above, or another material or combination of materials that support hole-electron recombination. The dopant is usually chosen from highly fluorescent dyes, but phosphorescent compounds, e.g., transition metal complexes as described in WO 98/55561, WO 00/18851, WO 00/57676, and WO 00/70655 are also useful. Dopants are typically coated as 0.01 to 10% by weight into the host material. Polymeric materials such as polyfluorenes and polyvinylarylenes (e.g., poly(p-phenylenevinylene), PPV) can also be used as the host material. In this case, small molecule dopants can be molecularly dispersed into the polymeric host, or the dopant could be added by copolymerizing a minor constituent into the host polymer.

[0076] An important relationship for choosing a dye as a dopant is a comparison of the bandgap potential which is defined as the energy difference between the highest occupied molecular orbital and the lowest unoccupied molecular orbital of the molecule. For efficient energy transfer from the host to the dopant molecule, a necessary condition is that the band gap of the dopant is smaller than that of the host material. For phosphorescent emitters it is also important that the host triplet energy level of the host be high enough to enable energy transfer from host to dopant.

[0077] Host and emitting molecules known to be of use include, but are not limited to, those disclosed in U.S. Pat.

Nos. 4,768,292; 5,141,671; 5,150,006; 5,151,629; 5,405,709; 5,484,922; 5,593,788; 5,645,948; 5,683,823; 5,755,999; 5,928,802; 5,935,720; 5,935,721; and 6,020,078.

[0078] Metal complexes of 8-hydroxyquinoline (oxine) and similar derivatives constitute one class of useful host compounds capable of supporting electroluminescence. Illustrative of useful chelated oxinoid compounds are the following:

[0079] CO-1: Aluminum trisoxine [alias, tris(8-quinolinolato)aluminum(III)]

[0080] CO-2: Magnesium bisoxine [alias, bis(8-quinolinolato)magnesium(II)]

[0081] CO-3: Bis[benzo {f}-8-quinolinolato]zinc (II)

[0082] CO-4: Bis(2-methyl-8-quinolinolato)aluminum(III)- μ -oxo-bis(2-methyl-8-quinolinolato) aluminum(III)

[0083] CO-5: Indium trisoxine [alias, tris(8-quinolinolato)indium]

[0084] CO-6: Aluminum tris(5-methyloxine) [alias, tris(5-methyl-8-quinolinolato) aluminum(II)]

[0085] CO-7: Lithium oxine [alias, (8-quinolinolato)lithium(I)]

[0086] CO-8: Gallium oxine [alias, tris(8-quinolinolato)gallium(III)]

[0087] CO-9: Zirconium oxine [alias, tetra(8-quinolinolato)zirconium(IV)]

[0088] Other classes of useful host materials include, but are not limited to: derivatives of anthracene, such as 9,10-di-(2-naphthyl)anthracene and derivatives thereof as described in U.S. Pat. No. 5,935,721, distyrylarylene derivatives as described in U.S. Pat. No. 5,121,029, and benzazole derivatives, for example, 2,2',2"-[(1,3,5-phenylene)tris[1-phenyl-1H-benzimidazole]]. Carbazole derivatives are particularly useful hosts for phosphorescent emitters.

[0089] Useful fluorescent dopants include, but are not limited to, derivatives of anthracene, tetracene, xanthene, perylene, rubrene, coumarin, rhodamine, and quinacridone, dicyanomethylenepyran compounds, thiopyran compounds, polymethine compounds, pyrilium and thiapyrilium compounds, fluorene derivatives, perflanthene derivatives, indenoperylene derivatives, bis(azinyl)amine boron compounds, bis(azinyl)methane compounds, and carbostyryl compounds.

[0090] Electron-Transporting Layer (ETL)

[0091] Preferred thin film-forming materials for use in forming the electron-transporting layer 111 of the organic EL elements of this invention are metal chelated oxinoid compounds, including chelates of oxine itself (also commonly referred to as 8-quinolinol or 8-hydroxyquinoline). Such compounds help to inject and transport electrons, exhibit high levels of performance, and are readily fabricated in the form of thin films. Exemplary oxinoid compounds were listed previously.

[0092] Other electron-transporting materials include various butadiene derivatives as disclosed in U.S. Pat. No. 4,356,429 and various heterocyclic optical brighteners as

described in U.S. Pat. No. 4,539,507. Benzazoles and triazines are also useful electron-transporting materials.

[0093] Cathode

[0094] When light emission is viewed solely through the anode, the cathode **113** used in this invention can be comprised of nearly any conductive material. Desirable materials have good film-forming properties to ensure good contact with the underlying organic layer, promote electron injection at low voltage, and have good stability. Useful cathode materials often contain a low work function metal (<4.0 eV) or metal alloy. One preferred cathode material is comprised of a Mg:Ag alloy wherein the percentage of silver is in the range of 1 to 20%, as described in U.S. Pat. No. 4,885,221. Another suitable class of cathode materials includes bilayers comprising a thin electron-injection layer (EIL) in contact with the organic layer (e.g., ETL) which is capped with a thicker layer of a conductive metal. Here, the EIL preferably includes a low work function metal or metal salt, and if so, the thicker capping layer does not need to have a low work function. One such cathode is comprised of a thin layer of LiF followed by a thicker layer of Al as described in U.S. Pat. No. 5,677,572. Other useful cathode material sets include, but are not limited to, those disclosed in U.S. Pat. Nos. 5,059,861; 5,059,862, and 6,140,763.

[0095] When light emission is viewed through the cathode, the cathode must be transparent or nearly transparent. For such applications, metals must be thin or one must use transparent conductive oxides, or a combination of these materials. Optically transparent cathodes have been described in more detail in U.S. Pat. No. 4,885,211, U.S. Pat. No. 5,247,190, JP 3,234,963, U.S. Pat. No. 5,703,436, U.S. Pat. No. 5,608,287, U.S. Pat. No. 5,837,391, U.S. Pat. No. 5,677,572, U.S. Pat. No. 5,776,622, U.S. Pat. No. 5,776,623, U.S. Pat. No. 5,714,838, U.S. Pat. No. 5,969,474, U.S. Pat. No. 5,739,545, U.S. Pat. No. 5,981,306, U.S. Pat. No. 6,137,223, U.S. Pat. No. 6,140,763, U.S. Pat. No. 6,172,459, EP 1 076 368, U.S. Pat. No. 6,278,236, and U.S. Pat. No. 6,284,393. Cathode materials are typically deposited by evaporation, sputtering, or chemical vapor deposition. When needed, patterning can be achieved through many well known methods including, but not limited to, through-mask deposition, integral shadow masking, for example, as described in U.S. Pat. No. 5,276,380 and EP 0 732 868, laser ablation, and selective chemical vapor deposition.

[0096] Other Common Organic Layers and Device Architecture

[0097] In some instances, layers **109** and **111** can optionally be collapsed into a single layer that serves the function of supporting both light emission and electron transportation. It is also known in the art that emitting dopants may be added to the hole-transporting layer, which may serve as a host. Multiple dopants may be added to one or more layers in order to create a white-emitting OLED, for example, by combining blue- and yellow-emitting materials, cyan- and red-emitting materials, or red-, green-, and blue-emitting materials. White-emitting devices are described, for example, in EP 1 187 235, US 20020025419, EP 1 182 244, U.S. Pat. No. 5,683,823, U.S. Pat. No. 5,503,910, U.S. Pat. No. 5,405,709, and U.S. Pat. No. 5,283,182.

[0098] Additional layers such as electron or hole-blocking layers as taught in the art may be employed in devices of this invention. Hole-blocking layers are commonly used to improve efficiency of phosphorescent emitter devices, for example, as in US 20020015859.

[0099] This invention may be used in so-called stacked device architecture, for example, as taught in U.S. Pat. No. 5,703,436 and U.S. Pat. No. 6,337,492.

[0100] Deposition of Organic Layers

[0101] The organic materials mentioned above are suitably deposited through a vapor-phase method such as sublimation, but can be deposited from a fluid, for example, from a solvent with an optional binder to improve film formation. If the material is a polymer, solvent deposition is useful but other methods can be used, such as sputtering or thermal transfer from a donor sheet. The material to be deposited by sublimation can be vaporized from a sublimator "boat" often comprised of a tantalum material, e.g., as described in U.S. Pat. No. 6,237,529, or can be first coated onto a donor sheet and then sublimed in closer proximity to the substrate. Layers with a mixture of materials can utilize separate sublimator boats or the materials can be pre-mixed and coated from a single boat or donor sheet. Patterned deposition can be achieved using shadow masks, integral shadow masks (U.S. Pat. No. 5,294,870), spatially-defined thermal dye transfer from a donor sheet (U.S. Pat. Nos. 5,688,551, 5,851,709 and 6,066,357) and inkjet method (U.S. Pat. No. 6,066,357).

[0102] Encapsulation

[0103] Most OLED devices are sensitive to moisture or oxygen, or both, so they are commonly sealed in an inert atmosphere such as nitrogen or argon, along with a desiccant such as alumina, bauxite, calcium sulfate, clays, silica gel, zeolites, alkaline metal oxides, alkaline earth metal oxides, sulfates, or metal halides and perchlorates. Methods for encapsulation and desiccation include, but are not limited to, those described in U.S. Pat. No. 6,226,890. In addition, barrier layers such as SiO_x, Teflon, and alternating inorganic/polymeric layers are known in the art for encapsulation.

[0104] Optical Optimization

[0105] OLED devices of this invention can employ various well-known optical effects in order to enhance its properties if desired. This includes optimizing layer thicknesses to yield maximum light transmission, providing dielectric mirror structures, replacing reflective electrodes with light-absorbing electrodes, providing anti glare or anti-reflection coatings over the display, or providing colored, neutral density, or color conversion filters over the display. Filters, and anti-glare or anti-reflection coatings may be specifically provided over the encapsulating cover or an electrode protection layer beneath the encapsulating cover.

[0106] The invention has been described in detail with particular reference to certain preferred embodiments thereof, but it will be understood that variations and modifications can be effected within the spirit and scope of the invention.

Parts List

- [0107] 10 OLED light emissive element
- [0108] 11 top-emitting OLED display device
- [0109] 12 organic light emitting layer
- [0110] 12R red-light emitting OLED layer
- [0111] 12G green-light emitting OLED layer
- [0112] 12B blue-light emitting OLED layer
- [0113] 14 second electrode layer
- [0114] 16 first electrode layer
- [0115] 18 power source
- [0116] 20 substrate
- [0117] 22 TFT active matrix layer
- [0118] 24 first insulating planarization layer
- [0119] 24' second insulating planarization layer
- [0120] 26 hole-injecting layer
- [0121] 27 hole-transporting layer
- [0122] 28 electron transporting layer
- [0123] 29 electron injection layer
- [0124] 32 electrode protection layer
- [0125] 34 cavity
- [0126] 36 encapsulating cover
- [0127] 50 circular polarizer
- [0128] 52 peripheral channel
- [0129] 70 adhesive
- [0130] 101 substrate
- [0131] 103 anode layer
- [0132] 105 hole-injecting layer
- [0133] 107 hole-transporting layer
- [0134] 109 light-emitting layer
- [0135] 111 electron-transporting layer
- [0136] 113 cathode layer

[0137] 250 voltage/current source

[0138] 260 conductive wiring

What is claimed is:

1. A top emitting OLED display comprising:

- a) a substrate;
- b) an array of OLED light emissive elements formed over the substrate;
- c) an encapsulating cover located over the OLED light emissive elements; and
- d) a circular polarizer located between the encapsulating cover and the OLED light emissive elements.

2. The OLED display claimed in claim 1, wherein the encapsulating cover defines a cavity over the OLED light emissive elements and the circular polarizer is attached to the encapsulating cover inside the cavity.

3. The OLED display claimed in claim 2, wherein the cavity defines a gap between the circular polarizer and the OLED light emissive elements.

4. The OLED display claimed in claim 3, wherein the gap is filled with an inert gas.

5. The OLED display claimed in claim 3, wherein the gap is filled with a transparent solid.

6. The OLED display claimed in claim 1, wherein the circular polarizer is attached to the OLED light emissive elements.

7. The OLED display claimed in claim 1, wherein the encapsulating cover is a flat plate, and further comprising means for hermetically sealing the perimeter of the plate to the substrate.

8. The OLED display claimed in claim 7, wherein the sealing means is light absorbing.

9. The OLED display claimed in claim 1, wherein the encapsulating cover is a flat plate, and further comprising means for hermetically sealing the plate to the substrate, the sealing means covering the entire display.

10 The OLED display claimed in claim 1, further comprising a desiccant material located around the perimeter of the encapsulating cover.

11. The OLED display claimed in claim 10, wherein the encapsulating cover defines a peripheral channel and the desiccant material is located in the channel.

* * * * *

专利名称(译)	带圆形偏光镜的Oled显示器		
公开(公告)号	US20040069985A1	公开(公告)日	2004-04-15
申请号	US10/271149	申请日	2002-10-15
[标]申请(专利权)人(译)	伊斯曼柯达公司		
申请(专利权)人(译)	伊士曼柯达公司		
当前申请(专利权)人(译)	伊士曼柯达公司		
[标]发明人	COK RONALD S		
发明人	COK, RONALD S.		
IPC分类号	H01L51/00 H01L51/30 H01L51/52 H01L35/24		
CPC分类号	H01L51/005 H01L51/0052 H01L51/0059 H01L51/0077 H01L51/5259 H01L51/5281 H01L2251/5315 H01L51/524 H01L51/0081		
外部链接	Espacenet USPTO		

摘要(译)

顶部发光OLED显示器包括基板;在衬底上形成的OLED发光元件阵列;封装盖位于OLED发光元件上方;圆形偏振器位于封装盖和OLED发光元件之间。

